# **ACPL-W60L and ACPL-K63L**



# High-Speed LVTTL Compatible 3.3V/5V Optocouplers

## **Data Sheet**

### **Description**

The ACPL-W60L/ACPL-K63L are optically coupled gates that combine a GaAsP light emitting diode and an integrated high gain photo detector. The output of the detector IC is an open collector Schottky-clamped transistor. The internal shield provides a guaranteed common mode transient immunity specification of 15 kV/µs at 3.3V.

This unique design provides maximum AC and DC circuit isolation while achieving LVTTL/LVCMOS compatibility. The optocoupler AC and DC operational parameters are guaranteed from –40°C to +100°C allowing trouble-free system performance.

#### CAUTION

It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD. The components featured in this data sheet are not to be used in military or aerospace applications or environments.

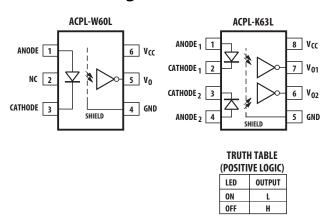
#### **Features**

- Dual Voltage Operation (3.3V/5V)
- Package clearance/creepage at 8 mm
- 15 kV/µs minimum Common Mode Rejection (CMR) at V<sub>CM</sub> = 1000V
- High speed: 15 MBd typical
- LVTTL/LVCMOS compatible
- Low input current capability: 5 mA
- Guaranteed AC and DC performance over temperature:
  -40°C to +100°C
- Available in 6-pin stretched SO-6 and 8 pin stretched SO-8
- Safety approvals: UL, CSA, IEC/EN/DIN EN 60747-5-5

## **Applications**

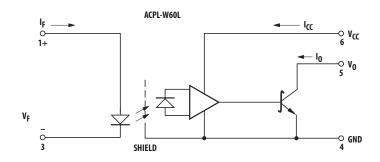
- Isolated line receiver
- Computer-peripheral interfaces
- Microprocessor system interfaces
- Digital isolation for A/D, D/A conversion
- Switching power supply
- Instrument input/output isolation
- Ground loop elimination
- Pulse transformer replacement
- Field bus

## **Functional Diagram**

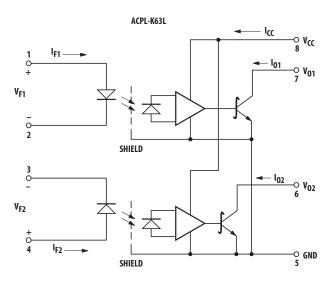


A  $0.1-\mu F$  bypass capacitor must be connected between pins 4 and 6 for ACPL-W60L, and pins 5 and 8 for ACPL-K63L.

## **Schematic Diagrams**



Bypassing of the power supply line is required, with a 0.1-µF ceramic disc capacitor adjacent to each optocoupler. Total lead length between both ends of the capacitor and the isolator pins should not exceed 20 mm.



These optocouplers are suitable for high-speed logic interfacing, input/output buffering, as line receivers in environments that conventional line receivers cannot tolerate and are recommended for use in extremely high ground or induced noise environments.

## **Ordering Information**

ACPL-W60L/-K63L is UL Recognized with 5000  $V_{rms}$  for 1 minute per UL1577 and is approved under CSA Component Acceptance Notice #5, File CA 88324.

	Option	•			UL 5000 Vrms/	IEC/EN/DIN		
Part Number	RoHS Compliant	Package	Surface Mount	Tape and Reel	1 Minute rating	EN 60747-5-5	Quantity	
ACPL-W60L	-000E	Stretched SO-6	X		X		100 per tube	
	-500E		Х	Х	X		1000 per reel	
	-560E		Х	Х	X	Х	1000 per reel	
ACPL-K63L	-000E	Stretched SO-8	Х		X		80 per tube	
	-500E		Х	Х	X		1000 per reel	
	-560E	]	Х	Х	Х	Х	1000 per reel	

To order, choose a part number from the part number column and combine with the desired option from the option column to form an order entry.

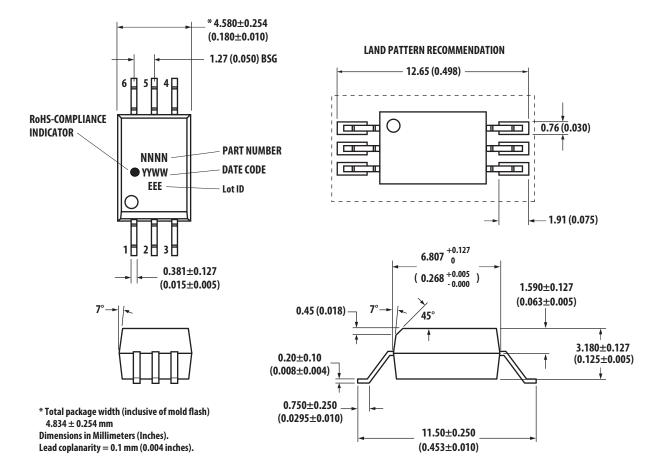
#### Example 1:

ACPL-W60L-560E to order product of Stretched SO-6 Surface Mount package in Tape and Reel packaging with IEC/EN/DIN EN 60747-5-5 Safety Approval in RoHS compliant.

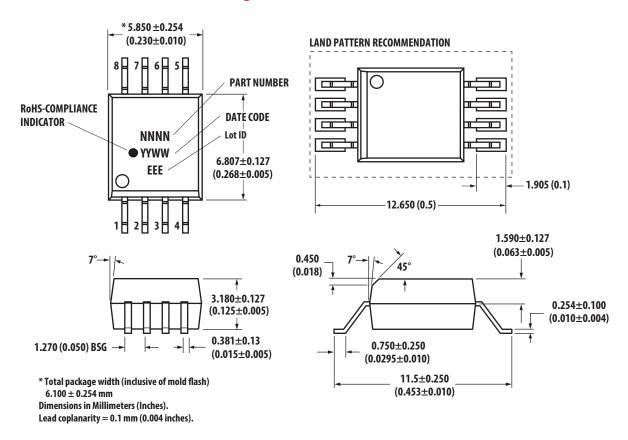
Option data sheets are available. Contact your Broadcom sales representative or authorized distributor for information.

## **Package Outline Drawings**

### **ACPL-W60L Stretched SO-6 Package**



#### **ACPL-K63L Stretched SO-8 Package**



### **Recommended Solder Reflow Thermal Profile**

Recommended reflow condition as per JEDEC Standard, J-STD-020 (latest revision). Non-halide flux should be used.

## **Regulatory Information**

The ACPL-W60L/K63L have been approved by the following organizations.

UL	Approval under UL 1577, Component Recognition Program, File E55361.
CSA	Approval under CSA Component Acceptance Notice #5, File CA 88324.
IEC/EN/DIN EN 60747-5-5	Approval/Pending Approval

## **Insulation and Safety-Related Specifications**

Parameter	Symbol	ACPL-W60L/ K63L	Units	Conditions
Minimum External Air Gap (External Clearance)	L (101)	8	mm	Measured from input terminals to output terminals, shortest distance through air.
Minimum External Tracking (External Creepage)	L (102)	8	mm	Measured from input terminals to output terminals, shortest distance path along body.
Minimum Internal Plastic Gap (Internal Clearance)		0.08	mm	Through insulation distance, conductor to conductor, usually the direct distance between the photoemitter and photodetector inside the optocoupler cavity.
Tracking Resistance (Comparative Tracking Index)	CTI	175	Volts	DIN IEC 112/VDE 0303 Part 1
Isolation Group		Illa	_	Material Group (DIN VDE 0110, 1/89, Table 1)

# **IEC/EN/DIN EN 60747-5-5 Insulation-Related Characteristics (Option x60E)**

Description	Symbol	Characteristic ACPL-W60L ACPL-K63L	Units
Installation classification per DIN VDE 0110/39, Table 1	•		
for rated mains voltage $\leq$ 150 $V_{rms}$		I-IV	
for rated mains voltage≤ 300 V <sub>rms</sub>		I-IV	
for rated mains voltage ≤ 600 V <sub>rms</sub>		I-III	
for rated mains voltage $\leq 1000  V_{rms}$		I-III	
Climatic Classification		55/100/21	
Pollution Degree (DIN VDE 0110/39)		2	
Maximum Working Insulation Voltage	VIORM	1140	$V_{peak}$
Input to Output Test Voltage, Method $b^a$ $V_{IORM} \times 1.875 = V_{PR}$ , 100% Production Test with $t_m = 1s$ , Partial Discharge $< 5$ pC	V <sub>PR</sub>	2137	$V_{peak}$
Input-to-Output Test Voltage, Method $a^a$ $V_{IORM} \times 1.6 = V_{PR,}$ Type and Sample Test, $t_m = 10s$ , Partial Discharge $< 5$ pC	V <sub>PR</sub>	1824	$V_{peak}$
Highest Allowable Overvoltage (Transient Overvoltage, t <sub>ini</sub> = 60s)	V <sub>IOTM</sub>	8000	$V_{peak}$
Safety Limiting Values – maximum values allowed in the event of a failure			
Case Temperature	T <sub>S</sub>	175	°C
Input Current	I <sub>S,INPUT</sub>	230	mA
Output Power	P <sub>S,OUTPUT</sub>	600	mW
Insulation Resistance at $T_S$ , $V_{IO} = 500 \text{ V}$	R <sub>S</sub>	≥ 10 <sup>9</sup>	Ω

a. Refer to the optocoupler section of the Isolation and Control Components Designer's Catalog, under Product Safety Regulations section, (IEC/EN/DIN EN 60747-5-5) for a detailed description of Method a and Method b partial discharge test profiles.

**NOTE** These optocouplers are suitable for "safe electrical isolation" only within the safety limit data. Maintenance of the safety limit data shall be ensured by means of protective circuits.

## Absolute Maximum Ratings (No Derating Required Up to 85°C)

Parameter	Symbol	Device <sup>a</sup>	Min.	Max.	Units	Note
Storage Temperature	$T_S$		-55	125	°C	
Operating Temperature†	T <sub>A</sub>		-40	100	°C	
Average Forward Input Current	I <sub>F</sub>	ACPL-W60L	_	20	mA	b
		ACPL-K63L	_	15		c, d
Reverse Input Voltage	V <sub>R</sub>		_	5	V	С
Input Power Dissipation	P <sub>I</sub>		_	40	mW	
Supply Voltage (1 Minute Maximum)	V <sub>CC</sub>		_	7	V	
Output Collector Current	Io		_	50	mA	С
Output Collector Voltage	V <sub>O</sub>		_	7	V	С
Output Power Dissipation	P <sub>O</sub>	ACPL-W60L	_	85	mW	
		ACPL-K63L	_	60		c e
Solder Reflow Temperature Profile				See Package O	utline Drawing	js

- a. Ratings apply to all devices except otherwise noted in the Package column.
- b. Peaking circuits may produce transient input currents up to 50 mA, 50-ns maximum pulse width, provided average current does not exceed 20 mA.
- c. Each channel.
- d. Peaking circuits may produce transient input currents up to 50 mA, 50-ns maximum pulse width, provided average current does not exceed 15 mA.
- e. Derate linearly above +80°C free-air temperature at a rate of 2.7 mW/°C.

## **Recommended Operating Conditions**

Parameter	Symbol	Min.	Max.	Units	Conditions
Input Current, Low Level	I <sub>FL</sub> <sup>a</sup>	0	250	μΑ	
Input Current, High Level <sup>b</sup>	I <sub>FH</sub> <sup>c</sup>	5	15	mA	
		6		mA	$2.7V \le V_{CC} \le 3.6V$ , $T_A = 85^{\circ}C \text{ to } 100^{\circ}C$
Power Supply Voltage	V <sub>CC</sub>	2.7	3.6	V	
		4.5	5.5	V	
Operating Temperature	T <sub>A</sub>	-40	100	°C	
Fan Out (at $R_L = 1 \text{ k}\Omega)^b$	N	_	5	TTL Loads	
Output Pull-up Resistor	$R_L$	330	4 k	Ω	

- a. The off condition can also be guaranteed by ensuring that  $V_{FL} \le 0.8$  volts.
- b. Each channel.
- c. At T<sub>A</sub> = -40°C to 85°C. The initial switching threshold is 5 mA or less. It is recommended that 6.3 mA to 10 mA be used for best performance and to permit at least a 20% LED degradation guardband.

# **Electrical Specifications**

Over recommended operating conditions ( $T_A = -40^{\circ}\text{C}$  to  $+100^{\circ}\text{C}$ ,  $2.7\text{V} \le \text{V}_{CC} \le 3.6\text{V}$ ) unless otherwise specified. All Typicals at  $\text{V}_{CC} = 3.3\text{V}$ ,  $T_A = 25^{\circ}\text{C}$ .

Parameter	Symbol	Device	Min.	Тур.	Max.	Units	Test Conditions	Figure	Note
High Level Output Current	I <sub>OH</sub>		_	4.5	50	μΑ	$V_{CC} = 3.3V, V_{O} = 3.3V, I_{F} = 250 \mu A$	1, 2	a
Input Threshold Current	I <sub>TH</sub>		_	3.0	5.0	mA	$T_A = -40$ °C to 85°C, $V_{CC} = 3.3$ V, $V_O = 0.6$ V, $I_{OL}$ (Sinking) = 13 mA	3, 4	
					6.0	mA	$V_{CC} = 3.3V, V_{O} = 0.6 V,$ $I_{OL}$ (Sinking) = 13 mA	3, 4	
Low Level Output Voltage	V <sub>OL</sub>		_	0.35	0.6	V	$V_{CC} = 3.3V$ , $I_F = 5$ mA, $I_{OL}$ (Sinking) = 13 mA	5, 6	
High Level Supply Current	I <sub>CCH</sub>	Single	_	4.7	7.0	mA	$I_F = 0 \text{ mA}$		
		Dual	_	6.9	10.0		V <sub>CC</sub> = 3.3V		
Low Level Supply Current	I <sub>CCL</sub>	Single	_	7.0	10.0	mA	I <sub>F</sub> = 10 mA		
		Dual	_	8.7	15.0		V <sub>CC</sub> = 3.3V		
Input Forward Voltage	V <sub>F</sub>		1.4	1.5	1.75	V	$T_A = 25$ °C, $I_F = 10$ mA	9	a
Input Reverse Breakdown Voltage	B <sub>VR</sub>		5		_	V	$I_R = 10 \mu A$		a
Input Diode Temperature Coefficient	$\Delta V_F / \Delta T_A$		_	-1.6	_	mV/°C	I <sub>F</sub> = 10 mA		a
Input Capacitance	C <sub>IN</sub>			60	_	pF	$f = 1 \text{ MHz}, V_F = 0V$		a

a. Each channel.

# **Electrical Specifications (DC)**

Over recommended operating conditions ( $T_A = -40^{\circ}\text{C}$  to  $+100^{\circ}\text{C}$ ,  $4.5\text{V} \le \text{V}_{DD} \le 5.5\text{V}$ ) unless otherwise specified. All typicals at  $V_{CC} = 5\text{V}$ ,  $T_A = 25^{\circ}\text{C}$ .

Parameter	Symbol	Device	Min.	Тур.	Max.	Units	Test Conditions	Figure	Note
High Level Output Current	I <sub>OH</sub>		_	5.5	100	μΑ	$V_{CC} = 5.5V, V_O = 5.5V, I_{FL} = 250 \mu A$	1, 2	a
Input Threshold Current	I <sub>TH</sub>		_	2.0	5.0	mA	$V_{CC} = 5.5V, V_O = 0.6 V, I_{OL} > 13 \text{ mA}$	3, 4	
Low Level Output Voltage	V <sub>OL</sub>		_	0.35	0.6	V	$V_{CC} = 5.5V$ , $I_F = 5$ mA, $I_{OL(Sinking)} = 13$ mA	5, 6	
High Level Supply Current	I <sub>CCH</sub>	Single	_	7.0	10.0	mA	$V_{CC} = 5.5V, I_F = 0 \text{ mA}$		
		Dual	_	10.0	15.0	mA	$V_{CC} = 5.5V, I_F = 0 \text{ mA}$		
Low Level Supply Current	I <sub>CCL</sub>	Single	_	9.0	13.0	mA	$V_{CC} = 5.5V, I_F = 10 \text{ mA}$		
		Dual	_	13.0	21.0	mA	$V_{CC} = 5.5V, I_F = 10 \text{ mA}$		
Input Forward Voltage	V <sub>F</sub>		1.4	1.5	1.75	V	$T_A = 25$ °C, $I_F = 10 \text{ mA}$	9	a
			1.3	_	1.8				
Input Reverse Breakdown Voltage	BV <sub>R</sub>		5	_	_	V	$I_R = 10 \mu A$		a
Input Diode Temperature Coefficient	$\Delta V_F / \Delta T_A$		_	-1.6	_	mV/°C	I <sub>F</sub> = 10 mA		a
Input Capacitance	C <sub>IN</sub>		_	60	_	pF	$f = 1 \text{ MHz}, V_F = 0 \text{ V}$		a

a. Each channel.

### **Switching Specifications**

Over recommended temperature ( $T_A = -40$ °C to +100°C),  $V_{CC} = 3.3$ V,  $I_F = 7.5$  mA unless otherwise specified. All Typicals at  $T_A = 25$ °C,  $V_{CC} = 3.3$ V.

Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions	Figure	Note
Propagation Delay Time to High Output Level	t <sub>PLH</sub>	_	_	90	ns	$T_A = -40$ °C to 85°C, $R_L = 350\Omega$ , $C_L = 15$ pF	10, 11, 12, 13, 14	a <sub>,</sub> b
		_	_	95	ns	$R_L = 350\Omega$ , $C_L = 15 pF$		
Propagation Delay Time to Low Output Level	t <sub>PHL</sub>	_	_	75	ns	$T_A = -40^{\circ}\text{C to }85^{\circ}\text{C}, R_L = 350\Omega, C_L = 15 \text{ pF}$		a c
Low Output Level		_	_	90	ns	$R_L = 350\Omega$ , $C_L = 15 pF$		
Pulse Width Distortion	t <sub>PHL</sub> -	_	_	25	ns	$T_A = -40$ °C to 85°C, $R_L = 350\Omega$ , $C_L = 15 \text{ pF}$	13, 14	d
	t <sub>PLH</sub>	_	_	30	ns	$R_L = 350\Omega, C_L = 15 \text{ pF}$		
Propagation Delay Skew	t <sub>PSK</sub>	_	_	40	ns			d <sub>,</sub> e
Output Rise Time (10–90%)	t <sub>r</sub>	_	45	_	ns			a
Output Fall Time (90–10%)	t <sub>f</sub>	_	20	_	ns			a

- a. Each channel.
- b. The t<sub>PLH</sub> propagation delay is measured from the 3.75 mA point on the falling edge of the input pulse to the 1.5-V point on the rising edge of the output pulse.
- c. The t<sub>PHI</sub> propagation delay is measured from the 3.75 mA point on the rising edge of the input pulse to the 1.5-V point on the falling edge of the output pulse.
- d. See test circuit for measurement details.
- e.  $t_{PSK}$  is equal to the worst case difference in  $t_{PLL}$  and/or  $t_{PLH}$  that will be seen between units at any given temperature and specified test conditions.

## **Switching Specifications (AC)**

Over recommended temperature ( $T_A = -40^{\circ}\text{C}$  to  $+100^{\circ}\text{C}$ ),  $V_{CC} = 5\text{V}$ ,  $I_F = 7.5$  mA unless otherwise specified. All Typicals at  $T_A = 25^{\circ}\text{C}$ ,  $V_{CC} = 5\text{V}$ .

Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions	Figure	Note
Propagation Delay Time to High Output Level	t <sub>PLH</sub>	20	48	75	ns	$T_A = 25$ °C, $R_L = 350\Omega$ , $C_L = 15 pF$	10, 11, 12, 13, 14	a b
		_		100	ns	$R_L = 350\Omega$ , $CL = 15 pF$		
Propagation Delay Time to Low Output Level	t <sub>PHL</sub>	25	50	75	ns	$T_A = 25$ °C, RL = 350 $\Omega$ , $C_L = 15$ pF		a c
Low Output Level		_		100	ns	$R_L = 350\Omega$ , $C_L = 15 pF$		
Pulse Width Distortion	t <sub>PHL</sub> -t <sub>PLH</sub>	_	3.5	35	ns	$R_L = 350\Omega$ , $C_L = 15 pF$	13, 14	d
Propagation Delay Skew	t <sub>psk</sub>	_		40	ns	$R_L = 350\Omega$ , $C_L = 15 pF$		d <sub>,</sub> e
Output Rise Time (10%-90%)	t <sub>r</sub>	_	24	_	ns	$R_L = 350\Omega, C_L = 15 \text{ pF}$		a
Output Fall Time (10%-90%)	t <sub>f</sub>	_	10	_	ns	$R_L = 350\Omega$ , $C_L = 15 pF$		a

- a. Each channel
- b. The t<sub>PLH</sub> propagation delay is measured from the 3.75 mA point on the falling edge of the input pulse to the 1.5-V point on the rising edge of the output pulse.
- c. The t<sub>PHL</sub> propagation delay is measured from the 3.75 mA point on the rising edge of the input pulse to the 1.5-V point on the falling edge of the output pulse.
- d. See test circuit for measurement details.
- e.  $t_{PSK}$  is equal to the worst case difference in  $t_{PHL}$  and/or  $t_{PLH}$  that will be seen between units at any given temperature and specified test conditions.

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Parameter	Symbol	Min.	Тур.	Units	Test Conditions	Figure	Note
Output High Level Common Mode Transient Immunity	CM <sub>H</sub>	15	25	kV/μs	$V_{CC} = 3.3V$ , $I_F = 0$ mA, $V_{O(MIN)} = 2V$ , $R_L = 350\Omega$ , $T_A = 25^{\circ}$ C, $V_{CM} = 1000V$ and $V_{CM} = 10V$	15	a b
Output Low Level Common Mode Transient Immunity	CM <sub>L</sub>	15	25	kV/μs	$V_{CC} = 3.3V$ , $I_F = 7.5$ mA, $V_{O(MAX)} = 0.8V$ , $R_L = 350\Omega$ , $T_A = 25$ °C, $V_{CM} = 1000V$ and $V_{CM} = 10V$	15	a, b
Output High Level Common Mode Transient Immunity	CM <sub>H</sub>	10	15	kV/μs	$V_{CC} = 5V$ , $I_F = 0$ mA, $V_{O(MIN)} = 2V$ , $R_L = 350\Omega$ , $T_A = 25^{\circ}$ C, $V_{CM} = 1000V$	15	a b
Output Low Level Common Mode Transient Immunity	CM <sub>L</sub>	10	15	kV/μs	$V_{CC} = 5V$ , $I_F = 7.5$ mA, $V_{O(MAX)} = 0.8V$ , $R_L = 350\Omega$ , $T_A = 25$ °C, $V_{CM} = 1000V$	15	c,b

- a. CM<sub>H</sub> is the maximum tolerable rate of rise on the common mode voltage to assure that the output will remain in a high logic state (that is, Vo > 2.0V).
- b. For sinusoidal voltages,  $(|dV_{CM}|/dt)_{max} = \pi f_{CM}V_{CM}$  (p-p).
- c. CM<sub>1</sub> is the maximum tolerable rate of fall of the common mode voltage to assure that the output will remain in a low logic state (that is, Vo < 0.8V).

### **Package Characteristics**

All Typicals at  $T_A = 25$ °C.

Parameter	Symbol	Package	Min.	Тур.	Max	Units	Test Conditions	Figure	Note
Input-Output Insulaton	II <sub>-O</sub> a	Single	_	_	1	μΑ	45% RH, t = 5s, V <sub>I-O</sub> = 3 kV DC, T <sub>A</sub> = 25°C		b, c
Input-Output Momentary Withstand Voltage <sup>a</sup>	V <sub>ISO</sub>	Single, Dual Channel	5000		_	Vrms	RH $\leq$ 50%, t = 1 min, T <sub>A</sub> = 25°C		b, c
Input-Output Resistance	R <sub>I-O</sub>	Single, Dual Channel	_	10 <sup>12</sup>	_	Ω	$V_{I-O} = 500 V_d c$		b,d,e
Input-Output Capacitance	C <sub>I-O</sub>	Single, Dual Channel	_	0.5	_	pF	f = 1 MHz, T <sub>A</sub> = 25°C		b, d, e
Input-Input Insulation Leakage Current	I <sub>I-I</sub>	Dual Channel	_	0.005	_	μΑ	RH $\leq$ 45%, t = 5s, V <sub>I-I</sub> = 500V		f
Resistance (Input-Input)	R <sub>I-I</sub>	Dual Channel	_	10 <sup>11</sup>	_	Ω			f
Capacitance (Input-Input)	C <sub>I-I</sub>	Dual Channel	_	0.25	_	pG	f = 1 MHz		f

- a. The Input-Output Momentary Withstand Voltage is a dielectric voltage rating that should not be interpreted as an input-output continuous voltage rating. For the continuous voltage rating refer to the IEC/EN/DIN EN 60747-5-5 Insulation Characteristics Table (if applicable), your equipment level safety specification or Broadcom Application Note 1074 entitled Optocoupler Input-Output Endurance Voltage.
- b. Single channel device is considered a two-terminal part when pins 1, 2, 3 are shorted together, and pins 4, 5, 6 shorted together separately. Dual channel device is considered a two-terminal part when pins 1, 2, 3, 4 are shorted together, and pins 5, 6, 7, 8 are shorted together separately.
- c. In accordance with UL 1577, each optocoupler is proof tested by applying an insulation test voltage  $\geq$  6000  $V_{rms}$  for one second (leakage detection current limit,  $I_{I-O} \leq 5 \mu A$ ). This test is performed before the 100% production test for partial discharge (Method b) shown in the IEC/EN/DIN EN 60747-5-5 Insulation Characteristics Table, if applicable.
- d. Each channel.
- e. Measured between the LED anode and cathode shorted together and pins 5 through 8 shorted together. For dual channel products only.
- f. Measured between pins 1 and 2 shorted together, and pins 3 and 4 shorted together. For dual channel products only.

Figure 1 Typical High Level Output Current vs. Temperature,  $V_{CC} = 3.3 V$ 

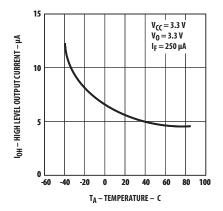


Figure 3 Typical Input Threshold Current vs Temperature,  $V_{CC} = 3.3 V$ 

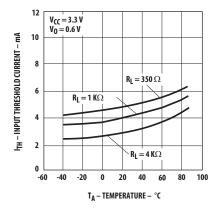


Figure 5 Typical Low Level Output Voltage vs. Temperature,  $V_{CC} = 3.3 V$ 

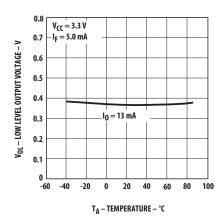


Figure 2 Typical High Level Output Current vs. Temperature,  $V_{CC} = 5V$ 

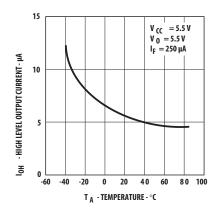


Figure 4 Typical Input Threshold Current vs Temperature,  $V_{CC} = 5V$ 

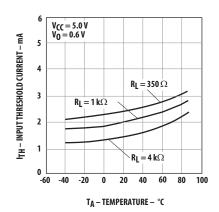


Figure 6 Typical Low Level Output Voltage vs. Temperature,  $V_{CC} = 5V$ 

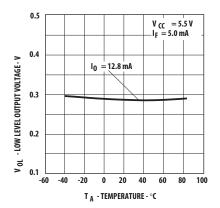


Figure 7 Typical Low Level Output Current vs. Temperature,  $V_{CC} = 3.3 V$ 

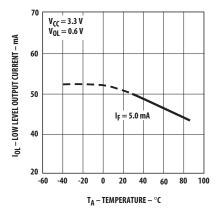
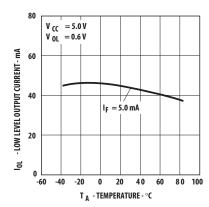


Figure 8 Typical Low Level Output Current vs. Temperature,  $V_{CC} = 5V$ 



**Figure 9 Typical Input Diode Forward Characteristic** 

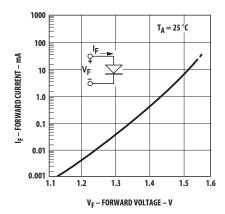


Figure 10 Test Circuit for  $t_{\text{PHL}}$  and  $t_{\text{PLH}}$ 

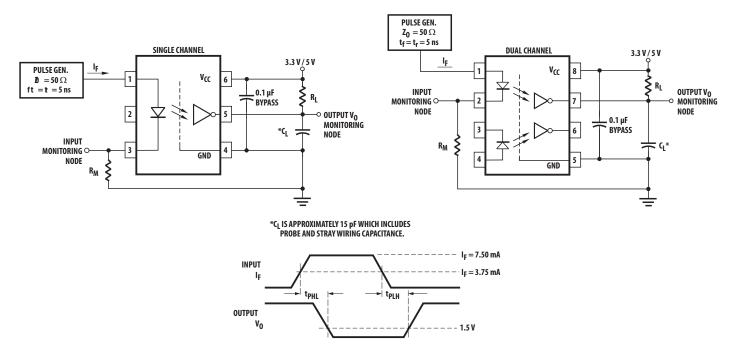


Figure 11 Typical Propagation Delay vs. Temperature  $V_{CC} = 3.3V$ 

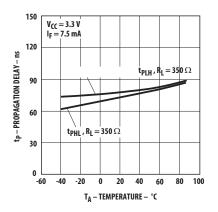


Figure 12 Typical Propagation Delay vs. Temperature  $V_{CC} = 5V$ 

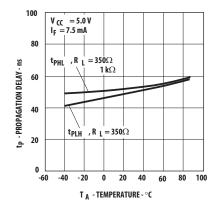


Figure 13 Typical Pulse Width Distortion vs. Temperature,  $V_{CC} = 3.3V$ 

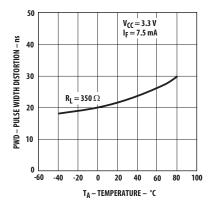


Figure 14 Typical Pulse Width Distortion vs. Temperature,  $V_{CC} = 5V$ 

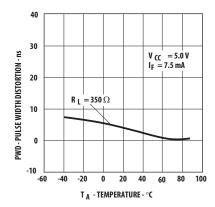
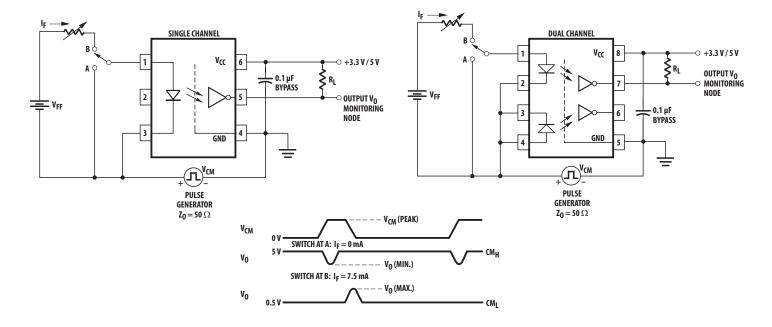


Figure 15 Test Circuit for Common Mode Transient Immunity and Typical Waveforms



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